

IngressGate™ - Two Way Active Drop Amplifier with Ingress suppression (patent p)

- √ Cost-effective Patent P. technology for ingress suppression.
- ✓ Drop amplifier integration.
- √ No need for expensive monitoring or useless detection.
- √ Simple integration outdoor or indoor.
- ✓ Plug and play device.
- √ Best performance in the market.

Safecom's new IngressGate™ is a revolutionary costeffective ingress suppression technology that enables CATV operators to increase upstream bandwidth and add advanced services with no interference.

Unlike standard solutions for ingress detection and monitoring, Safecom's patent-pending technology eliminates 70-90% of the ingress noise by addressing the source of the problem where most ingress noise is created - at the customer premises.









How it works?

Safeom's patented technology is based on the burst nature of the return path and the random presence of ingress noise. The technology functions as a upstream gateway that allows carrier signals from customer premises into the network only when the home devices are actively transmitting. This mode of operation eliminates most of the ingress noise without any adverse effect on the upstream and downstream signals.

Safecom's Ingress gate $^{\text{TM}}$ (patent p) technology supports DOCSIS 3.0 that requires switching speed faster than 1.6 μ S and ensures the most reliable and cost effecting solution for upstream ingress noise.

Ingress Gate drop amplifiers	Common Drop amplifiers (active return)			
The average noise floor at customer houses -59dB (mV)	The average noise floor at customer houses -59dB (mV)			
A: Typical drop amplifier NF is + 7 dB B: typical Amp gain-upstream +10dB C: ingress gate isolation is (type A) -35dB Results – Noise decrease less -18 dB	A: Typical drop amplifier NF is + 7 dB B: typical Amp gain-upstream +10dB Results – Noise increase almost +17 dB			
Noise level *(calculated) = -77dB (mV) * Floor noise	Noise level (upstream) –42dB (mV)			

For improving system implementation and reducing cost integrated ingress protection drop amplifier enables the simplest way to resolve the ingress problems while at the same time saving the need for additional common drop amplifiers.

Safecom offer range of Ingress gate solutions with or /without RF gain at the upstream /downstream.

Note:

- 1) Input forward flat 10dBmV, 77 channels 6MHz
- 2) Input return (upstream) 2 un modulated series carriers @ 27, 33MHz, out level 58dBmV.
- 3) One carrier wave un-modulation.
- 4) During the period that upstream gate is open.

Upstream Ingress Protection with RF Active forward/return gain Electric Performance- pocsis 3 READY

Model				IGDA1010 TA/TE/MA		IGDA1510 TA/TE/MA			
Ingress Gate Parameter			Unit	Min value	Max value	Min value	Max value		
Gate upstream level ⁴			dBmV	20		20			
Gate upstream time		μs		1.5		1.5			
Gate insert loss		dB		1.5		1.5			
Gate switch isolation		dB	35dB-A/15dB-B		35db-A/15dB-B				
Forward	(downstre	am) path							
Frequency range		MHz	47/54/70/85	1000	47/54/70/85	1000			
Gain		dB	10		14				
Flatness		dB		1.0		1.0			
Output level ¹		dΒμV		80		85			
Noise figure		dB		4.0		4.0			
Group	Front 1st chl		ns		25		25		
delay	2 nd chl		ns		10		10		
,	From 3th chl		ns		5		5		
CTB ¹		dBc		-73		-73			
CSO ¹		dBc		-62		-62			
Cross modulation ¹		dBc		-75		-75			
Reverse	(upstream) path							
Frequency range		MHz	5	30/47/55/65	5	30/47/55/65			
Gain		dB	10		10				
Flatness		dB		1.0		1.0			
Max output level		dBmV	60		60				
Noise figure		dB		6.8		6.8			
Group	5MHz		ns		20		20		
delay	Within band		ns		25		25		
	Middle ²		ns		5		5		
	nodulation		dBc		-70		-70		
	2	Forward	dBmV		-40		-40		
3 rd Inter n	nodulation		dBc		-60		-60		
	2	Forward	dBmV		-35		-35		
Cross modulation 3		dBc		-75		-75			
	performan	ce							
Resistance		Ohm	75						
Return loss		dB	18						
Hum modulation		dBc	-75						
RFI shielding		dB	100						
Surge withstand		RF input	IEEE C62.41 B3 6kV/300kA combo wave+A3 6kV/ ring wave						
		Other ports	IEEE C62.41 Category A36kV/ ring wave						
Power consumption ⁴		mA	1	320					
Waterproof		kg/cm ²	1						
F port conductor Gold-plated, beryllium			360° pin structure, push or pull force≥ 8 Newton .						
Measurement		mm	85×75×23						
Weight			g		350				